March 2009



# FGH40N60SF 600V, 40A Field Stop IGBT

### **Features**

- High current capability
- ٠ Low saturation voltage: V<sub>CE(sat)</sub> =2.3V @ I<sub>C</sub> = 40A
- High input impedance •
- Fast switching •
- RoHS compliant •

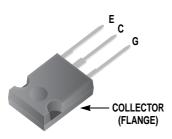
### Applications

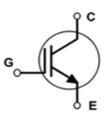
Inverter, UPS, SMPS, PFC



# **General Description**

Using Novel Field Stop IGBT Technology, Fairchild's new sesries of Field Stop IGBTs offer the optimum performance for Inverter, UPS, SMPS and PFC applications where low conduction and switching losses are essential.





### **Absolute Maximum Ratings**

Symbol	Description		Ratings	Units	
V <sub>CES</sub>	Collector to Emitter Voltage		600	V	
V <sub>GES</sub>	Gate to Emitter Voltage		± 20	V	
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 25 <sup>o</sup> C	80	A	
	Collector Current	@ T <sub>C</sub> = 100°C	40	А	
I <sub>CM (1)</sub>	Pulsed Collector Current	@ T <sub>C</sub> = 25 <sup>o</sup> C	120	A	
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	290	W	
	Maximum Power Dissipation	@ T <sub>C</sub> = 100 <sup>o</sup> C	116	W	
TJ	Operating Junction Temperature		-55 to +150	°C	
T <sub>stg</sub>	Storage Temperature Range		-55 to +150	°C	
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Notes: 1: Repetitive rating: Pulse width limited by max. junction temperature

### **Thermal Characteristics**

Symbol	Parameter	Тур.	Max.	Units	
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	0.43	°C/W	
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	-	40	°C/W	

Device N	larking Davias P		Packaging		Otv pe			Max Qty	
Device Marking Device P   FGH40N60SF FGH40N60SFTU		ackageTypeTO-247Tube		Qty per Tube 30ea		per Box			
FGH40i	10035	FGH40N003FT0	10-247	edur	30	Jea		-	
Electric	al Cha	racteristics of the l	<b>GBT</b> T <sub>C</sub> = 25°C	C unless otherwise noted					
Symbol		Parameter	Test C	Conditions	Min.	Тур.	Max.	Units	
Off Charac	teristics								
BV <sub>CES</sub>	Collector	to Emitter Breakdown Voltage	$V_{GE} = 0V, I_C =$	= 250μA	600	-	-	V	
ΔBV <sub>CES</sub> ΔT <sub>J</sub>	Temperat Voltage	ure Coefficient of Breakdown		$V_{GE} = 0V, I_C = 250\mu A$ $V_{CE} = V_{CES}, V_{GE} = 0V$		0.6	-	V/ºC	
I <sub>CES</sub>	Collector	Cut-Off Current	V <sub>CE</sub> = V <sub>CES</sub> , V			-	250	μA	
I <sub>GES</sub>	G-E Leak	age Current	$V_{GE} = V_{GES}, V_{CES}$		-	-	±400	nA	
On Charac	aristics					1			
V <sub>GE(th)</sub>		shold Voltage	I <sub>C</sub> = 250μA, V <sub>CE</sub> = V <sub>GE</sub>		4.0	5.0	6.5	V	
02(11)			$I_{\rm C} = 40$ A, $V_{\rm GE} = 15$ V		-	2.3	2.9	V	
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage		$I_{C} = 40A, V_{GE} = 15V,$ $T_{C} = 125^{\circ}C$		-	2.5	-	V	
Dynamic C	haracteris	tics	1 -		-			ļ	
C <sub>ies</sub>	Input Cap				-	2110	-	pF	
C <sub>oes</sub>	Output Ca	apacitance	V <sub>CE</sub> = 30V, V <sub>G</sub> f = 1MHz	$V_{CE} = 30V_{,} V_{GE} = 0V_{,}$		200	-	pF	
C <sub>res</sub>	Reverse <sup>-</sup>	Transfer Capacitance	T = TWHZ		-	60	-	pF	
Switching	Character	intion			T				
Switching (	1	Delay Time			-	25	-	ns	
t <sub>r</sub>	Rise Time		-		-	42	-	ns	
t <sub>d(off)</sub>		Delay Time	V <sub>CC</sub> = 400V, I	40Δ	-	115	-	ns	
t <sub>f</sub>	Fall Time	,	$R_G = 10\Omega, V_G$	<sub>E</sub> = 15V,	-	27	54	ns	
E <sub>on</sub>	Turn-On S	Switching Loss	Inductive Load	d, T <sub>C</sub> = 25°C	-	1.13	-	mJ	
E <sub>off</sub>		Switching Loss	-		-	0.31	-	mJ	
E <sub>ts</sub>	Total Swit	ching Loss	-		-	1.44	-	mJ	
t <sub>d(on)</sub>	Turn-On I	Delay Time			-	24	-	ns	
t <sub>r</sub>	Rise Time	9	1		-	43	-	ns	
t <sub>d(off)</sub>	Turn-Off I	Delay Time	V <sub>CC</sub> = 400V, I <sub>0</sub>	<sub>C</sub> = 40A,	-	120	-	ns	
t <sub>f</sub>	Fall Time		R <sub>G</sub> = 10Ω, V <sub>G</sub>	$R_G = 10\Omega$ , $V_{GE} = 15V$ , Inductive Load, $T_C = 125^{\circ}C$		30	-	ns	
	Turn-On S	Switching Loss	Inductive Load			1.14	-	mJ	
Eon			1		-	0.48	-	mJ	
	Turn-Off S	Switching Loss							
E <sub>off</sub>		Switching Loss	_		-	1.62	-	mJ	
E <sub>on</sub> E <sub>off</sub> E <sub>ts</sub> Q <sub>g</sub>		ching Loss			-		-	mJ nC	

# **Typical Performance Characteristics**



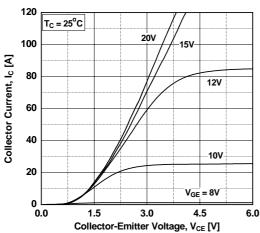


Figure 3. Typical Saturation Voltage Characteristics

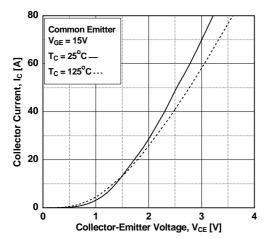


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

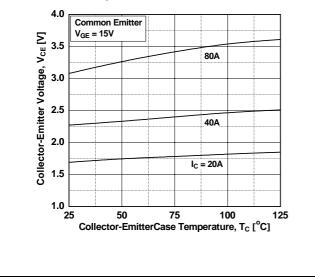
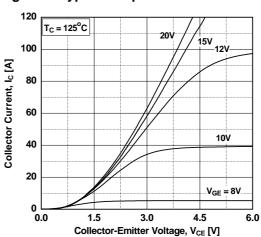


Figure 2. Typical Output Characteristics



**Figure 4. Transfer Characteristics** 

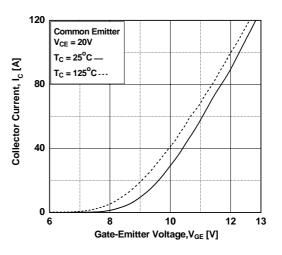
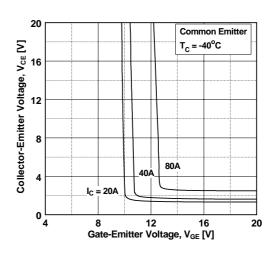
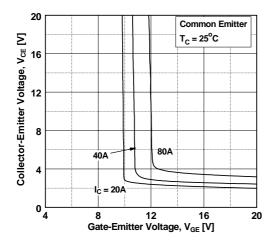


Figure 6. Saturation Voltage vs. V<sub>GE</sub>



## **Typical Performance Characteristics**

Figure 7. Saturation Voltage vs. V<sub>GE</sub>



**Figure 9. Capacitance Characteristics** 

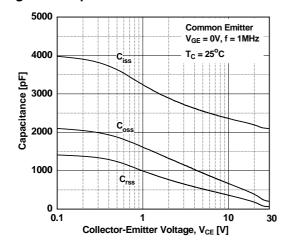


Figure 11. SOA Characteristics

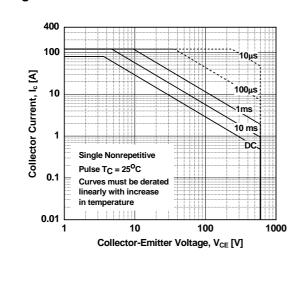


Figure 8. Saturation Voltage vs. V<sub>GE</sub>

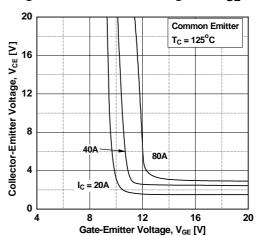


Figure 10. Gate charge Characteristics

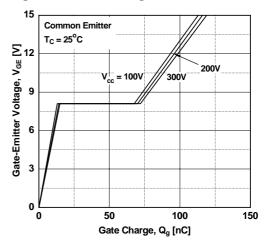
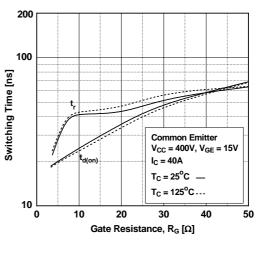
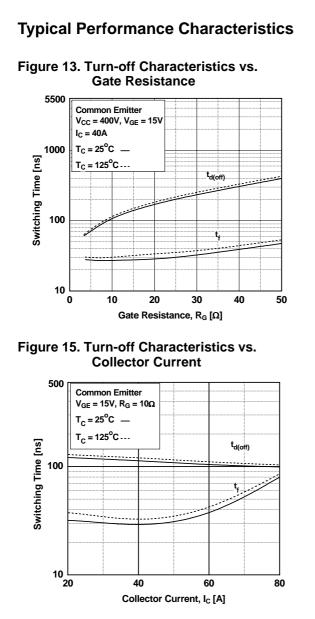
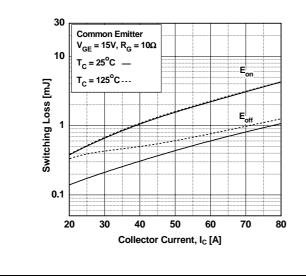


Figure 12. Turn-on Characteristics vs. Gate Resistance









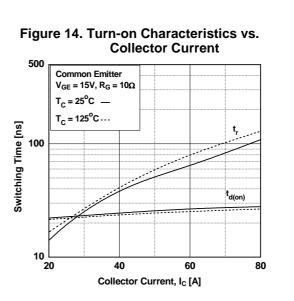


Figure 16. Switching Loss vs. Gate Resistance

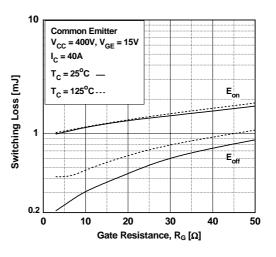
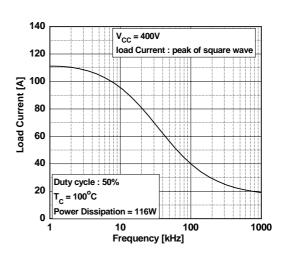
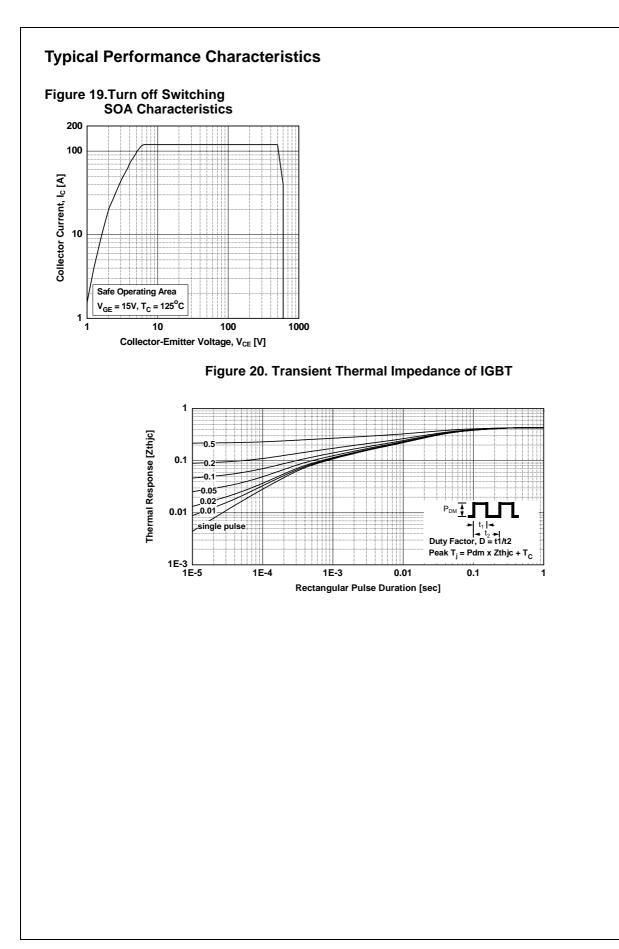
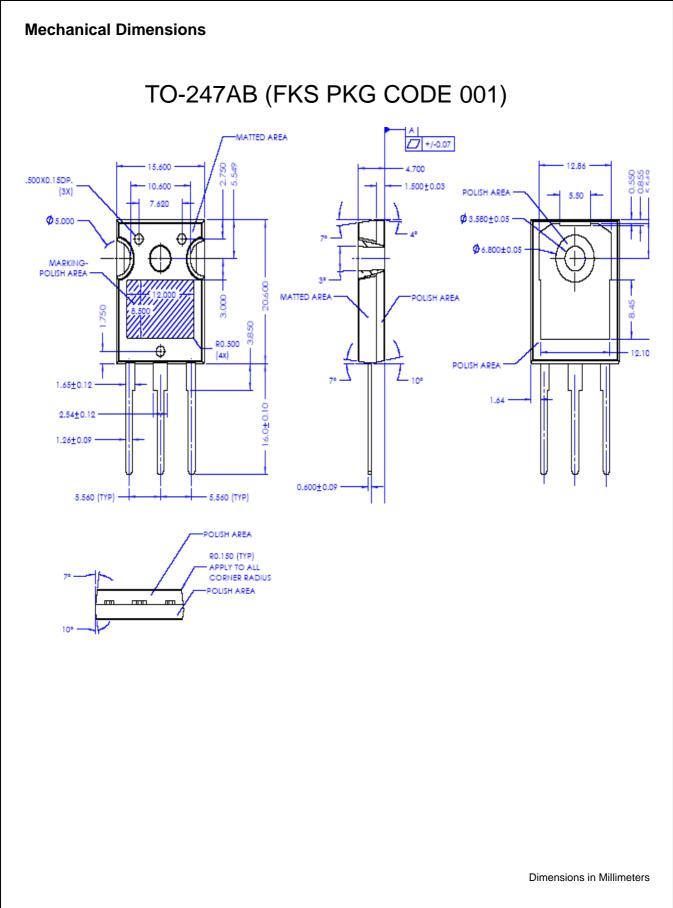


Figure 18. Load Current vs. Frequency



#### FGH40N60SF Rev. A





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